

# UNISONIC TECHNOLOGIES CO., LTD

UC4107 Preliminary CMOS IC

# TWO-STAGE HYSTERETIC LED DRIVER CONTROLLER

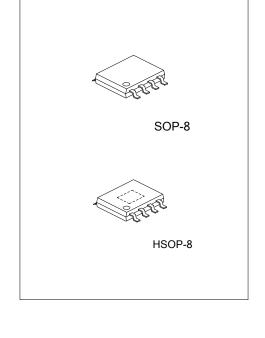
#### DESCRIPTION

The UTC **UC4107** is a two-stage controller with dual gate drivers consist of a Boost converter and a Buck converter. The advantage of the two-stage topology is highly compatible with Electronic Transformer in MR16/AR111 lighting market field applications.

The UTC **UC4107** is equipped with dual output gate drivers for external power MOSFETs, suitable for higher power applications.

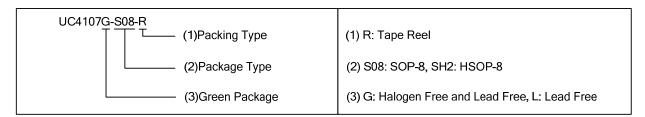
#### ■ FEATURES

- \* Topology: Boost+Buck
- \* Input Voltage Range: 4.5V~40V
- \* Adjustable Peak Input Current Control
- \* Adjustable Boost Output Voltage
- \* Independent Dual Stage Function
- \* Adjustable LED Current
- \* LED Current Accuracy: ±5%
- \* Input Under Voltage Lockout Detection
- \* Thermal Shutdown Protection

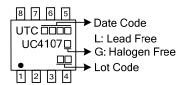


#### ORDERING INFORMATION

Ordering Number		Dookogo	Dooking	
Lead Free	Halogen Free	Package	Packing	
UC4107L-S08-R	UC4107G-S08-R	SOP-8	Tape Reel	
UC4107L-SH2-R	UC4107G-SH2-R	HSOP-8	Tape Reel	

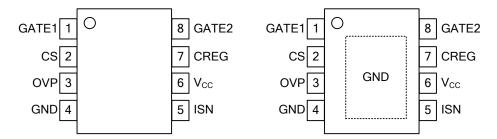


## MARKING



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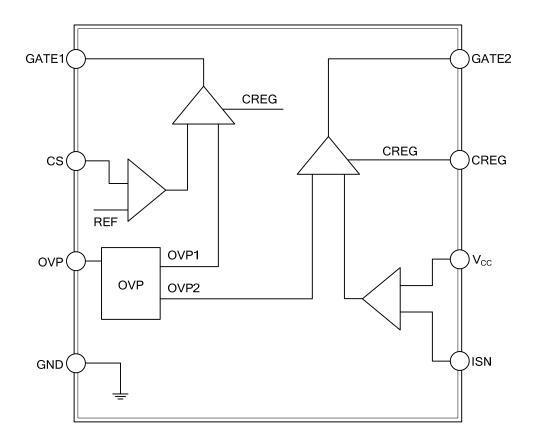
### ■ PIN CONFIGURATION



### ■ PIN DESCRIPTION

PIN NO.	PIN NAME	DESCRIPTION
1	GATE1	Gate Driver Output for External MOSFET Switch in the First Stage.
2	CS	Current Sense Input for External MOSFET Switch.
3	OVP	Over Voltage Protection Sense Input.
4	GND	Ground.
5	ISN	LED Current Sense Amplifier Negative Input.
6	V <sub>CC</sub>	Supply Voltage Input. For good bypass, place a ceramic capacitor near the VCC pin.
7	CREG	Internal Regulator Output. Place an 1µF capacitor between the CREG and GND pins.
8	GATE2	Gate Driver Output for External MOSFET Switch in the Second Stage.

### ■ BLOCK DIAGRAM



### ■ ABSOLUTE MAXIMUM RATING (T<sub>A</sub>=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Input Voltage, V <sub>CC</sub> to GND		-0.3 ~ 45	V
CS, GATE1, GATE2, CREG, OVP to GND		-0.3 ~ 6	V
V <sub>CC</sub> To ISN	V <sub>ISN</sub>	-1 ~ 3	V
Power Dissipation, @ T <sub>A</sub> =25°C	$P_{D}$	0.53	W
Junction Temperature	$T_J$	+150	°C
Storage Temperature Range	T <sub>STG</sub>	-65 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

#### ■ RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Input Voltage	Vcc	4.5 ~ +40	V
Junction Temperature Range	$T_J$	-40 ~ +125	°C
Ambient Temperature Range	T <sub>A</sub>	-40 ~ +85	°C

#### ■ THERMAL DATA

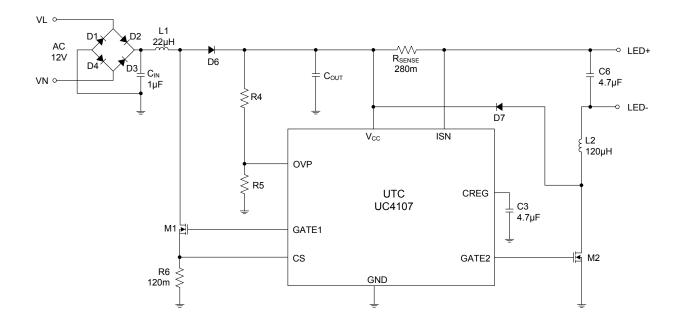
PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	$\theta_{JA}$	188	°C/W

### ■ ELECTRICAL CHARACTERISTICS

( $V_{\text{CC}}$ =10V, No Load,  $C_{\text{LOAD}}$ =1nF,  $T_{\text{A}}$ =25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
CREG UVLO_ON	V <sub>UVOL_ON</sub>	CS/OVP=0V	4	4.3	4.6	V
CREG UVLO_OFF	V <sub>UVOL OFF</sub>	CS/OVP=0V		4.2		V
V <sub>CC</sub> Shutdown Current	I <sub>SHDN</sub>	Before Start-Up, V <sub>CC</sub> =3.5V		10		μΑ
V <sub>CC</sub> Quiescent Current	ΙQ	After Start-Up, V <sub>CC</sub> =5V, GATE1 and GATE2 Stand Still		1.5		mA
Internal Reference Voltage	$V_{CREG}$			5		V
Internal Reference Voltage		I <sub>CREG</sub> =20mA		4.9		V
CS Threshold Voltage	V <sub>CS</sub>		215	240	265	mV
CS Pin Leakage Current	I <sub>CS</sub>			1		μΑ
OVP High Level	V <sub>OVP_H</sub>		1.71	1.9	2.09	V
OVP Low Level	$V_{OVP\_L}$		1.44	1.6	1.76	V
OVP Pin Leakage Current	I <sub>OVP</sub>			1		μΑ
GATE1 Duty Off-Time				1.5		μs
UGATE1 Drive Sink	R <sub>UGATE1sk</sub>	Sink=50mA		2		Ω
LGATE1 Drive Source	R <sub>LGATE1sr</sub>	Source=-50mA		1.25		Ω
GATE1 Default Pull Down Resistor				90		kΩ
ISN Threshold	$V_{ISN}$		123.5	130	136.5	mV
ISN Hysteresis	$\Delta V_{ISN}$		10	15	20	%
ISN Pin Leakage Current	I <sub>ISN</sub>			1		μΑ
UGATE2 Drive Sink	R <sub>UGATE2sk</sub>	Sink=50mA		2		Ω
LGATE2 Drive Source	R <sub>LGATE2sr</sub>	Source=-50mA		1.25		Ω
GATE2 Default Pull Down Resistor				90		kΩ
Thermal Shutdown Temperature	T <sub>SD</sub>		140	155	170	°C
Thermal Shutdown Hysteresis	$\Delta T_{SD}$			35		°C

#### ■ TYPICAL APPLICATION CIRCUIT



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